L	Hits	Search Text	DB	Time stamp
Number				
105	70	<pre>@ad<=20000731 and 'SGT' and (257/\$).ccls. and (438/\$).ccls.</pre>	USPAT; US-PGPUB;	2003/06/17 08:07
172	1037	(257/401).ccls. and @ad<=20000731	EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2003/06/17 08:23
173	43	(438/284).ccls. and @ad<=20000731	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2003/06/17 08:23
-	6	(("5637884") or ("5811324")).PN.	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2003/06/16 15:17
_	6	(("4979014") or ("5466621")).PN.	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/05/07 14:38
_	382	(257/900).CCLS.	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/05/07 14:39
-	378	((257/900).CCLS.) and @ad<=20000731	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2003/02/26 09:35
-	234007	(("257") or ("438")).CLAS.	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/05/07 14:44
-	682	(((257/\$) or (438/\$)).CCLS.) and @ad<=20000731 and 'convex' with 'layer'	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/05/07 14:49
_	1	"5095347".PN.	IBM_TDB USPAT	2002/05/07 14:46
_	1	"5095347".PN.	USPAT	2002/05/07 14:46
_	1	"5120666".PN.	USPAT	2002/05/07
_	1	"4774196".PN.	USPAT	2002/05/07
-	1	"5410172".PN.	USPAT	2002/05/07 14:47
-	1	"5420055".PN.	USPAT	2002/05/07 14:47
-	1	"5578513".PN.	USPAT	2002/05/07 14:47
_	1	"5580802".PN.	USPAT	2002/05/07
-	610	(((257/\$) or (438/\$)).CCLS.) and @ad<=20000731 and 'convex' with 'semiconductor'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/05/07

		•		
_	0	(((257/\$) or (438/\$)).CCLS.) and @ad<=20000731 and 'convex	USPAT; US-PGPUB;	2002/05/07 14:52
		semiconductor' and 'side-wall gate'	EPO; JPO; DERWENT; IBM TDB	
-	0	(((257/\$) or (438/\$)).CCLS.) and	USPAT;	2002/05/07
		<pre>@ad<=20000731 and 'convex semiconductor' and 'side wall gate'</pre>	US-PGPUB; EPO; JPO;	14:53
			DERWENT; IBM TDB	
_	1531	(((257/\$) or (438/\$)).CCLS.) and	USPAT;	2002/05/07
		@ad<=20000731 and 'side wall gate'	US-PGPUB;	14:57
			EPO; JPO; DERWENT;	
_	40	(((((257/\$) or (438/\$)).CCLS.) and	IBM_TDB USPAT;	2002/05/07
		@ad<=20000731 and 'side wall gate') and	US-PGPUB;	15:09
		'convex'	EPO; JPO; DERWENT;	
			IBM TDB	
-	238	(257/394).CCLS.	USPAT;	2002/05/07
			US-PGPUB; EPO; JPO;	15:12
			DERWENT;	
_	232	(257/394).ccls. and @ad<=20000731	IBM_TDB USPAT;	2002/05/07
			US-PGPUB;	15:43
			EPO; JPO; DERWENT;	
			IBM_TDB	}
-	1	"4979014".PN.	USPAT	2002/05/07 15:30
-	1	"5463241".PN.	USPAT	2002/05/07
-	1	"5512770".PN.	USPAT	2002/05/07
-	156	(257/262).ccls. and @ad<=20000731	USPAT; US-PGPUB;	2002/05/07
			EPO; JPO; DERWENT;	
			IBM_TDB	
-	17	'trench isolated transistor'	USPAT; US-PGPUB;	2002/05/07
			EPO; JPO;	13.37
			DERWENT;	
_	17	trench adj isolated adj transistor	IBM_TDB USPAT;	2002/05/07
			US-PGPUB;	16:18
			EPO; JPO; DERWENT;	
			IBM_TDB	
-	1	"4449285".PN.	USPAT	2002/05/07 15:59
	1	"4606011".PN.	USPAT	2002/05/07 15:59
-	1	"4670768".PN.	USPAT	2002/05/07
-	1	"4449285".PN.	USPAT	2002/05/07
-	1	"4606011".PN.	USPAT	2002/05/07
_	1	"4670768".PN.	USPAT	2002/05/07
-	1	"4801988".PN.	USPAT	2002/05/07
-	1	"4833516".PN.	USPAT	2002/05/07
-	1	"4910567".PN.	USPAT	2002/05/07
-	1	"5013679".PN.	USPAT	2002/05/07 16:12
L	l	<u></u>	l	++-

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-	1	"5013679".PN.	USPAT	2002/05/07
-	1	"5264716".PN.	USPAT	2002/05/07
-	1	"5289027".PN.	USPAT	16:12 2002/05/07
-	1	"5348905".PN.	USPAT	16:12 2002/05/07
_	1	"5360758".PN.	USPAT	16:13 2002/05/07
_	1	"5404037".PN.	USPAT	16:13 2002/05/07
_	1	"5567962".PN.	USPAT	16:13 2002/05/07
-	1	"5567962".PN.	USPAT	16:13 2002/05/07
_	1	"5567962".PN.	USPAT	16:13 2002/05/07
_	1	"5675164".PN.	USPAT	16:14 2002/05/07
_	1	"5909044".PN.	USPAT	16:14 2002/05/07
_	1	"5990510".PN.	USPAT	16:15 2002/05/07
_	1	"5994197".PN.	USPAT	16:15 2002/05/07
_	1	"5994729".PN.	USPAT	16:15 2002/05/07
-	1	"5998820".PN.	USPAT	16:15
_	1	"5998821".PN.	USPAT	16:16 2002/05/07
_	1	"6008513".PN.	USPAT	16:16 2002/05/07
_	1	"6020609".PN.	USPAT	16:16 2002/05/07
-	1	"6025620".PN.	USPAT	16:17 2002/05/07
_	1	"6037210".PN.	USPAT	16:17 2002/05/07
-	2781	side adj wall adj gate	USPAT;	16:17 2002/05/07
			US-PGPUB; EPO; JPO;	16:26
			DERWENT; IBM_TDB	0000/05/07
-	46	(side adj wall adj gate) and @ad<=20000731 and 'convex'	USPAT; US-PGPUB;	2002/05/07 16:23
			EPO; JPO; DERWENT;	
_	80	'side-wall' adj gates	IBM_TDB USPAT;	2002/05/07
			US-PGPUB; EPO; JPO;	16:27
			DERWENT; IBM_TDB	0000/05/05
-	77	('side-wall' adj gates) and @ad<=20000731	USPAT; US-PGPUB;	2002/05/07
			EPO; JPO; DERWENT;	
-	24	'convex semiconductor layer'	IBM_TDB USPAT;	2002/05/08
			US-PGPUB; EPO; JPO;	07:58
		_	DERWENT; IBM_TDB	
_	24	'convex semiconductor layer'	USPAT; US-PGPUB;	2002/05/08 08:13
			EPO; JPO; DERWENT;	
	<u> </u>		IBM_TDB	1

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-	1	"3278789".PN.	USPAT	2002/05/08 08:10
-	1	"3663857".PN.	USPAT	2002/05/08
_	1	"3735186".PN.	USPAT	08:10
_	1	"4093562".PN.	USPAT	08:10 2002/05/08
_	1	"4325084".PN.	USPAT	08:10 2002/05/08
_	1	"5066883".PN.	USPAT	08:10 2002/05/08
_	1	"3805123".PN.	USPAT	08:11 2002/05/08
_	1	"5753966".PN.	USPAT	08:11 2002/05/08
_	1	"5753966".PN.	USPAT	08:11 2002/05/08
_	1	"5814532".PN.	USPAT	08:12 2002/05/08
_	1	"5972730".PN.	USPAT	08:12 2002/05/08
_	1	"6037210".PN.	USPAT	08:12 2002/05/08
_	1	"6025620".PN.	USPAT	08:31 2002/05/08
_	1	"6020609".PN.	USPAT	08:31 2002/05/08
_	1	"5998821".PN.	USPAT	08:31 2002/05/08
_	155	'projection' near 'semiconductor	USPAT;	08:31 2002/05/08
		substrate'	US-PGPUB; EPO; JPO;	08:46
	1		DERWENT; IBM TDB	
-	143	('projection' near 'semiconductor substrate') and @ad<=20000731	USPAT; US-PGPUB;	2002/05/08
			EPO; JPO; DERWENT;	
_	799	(257/192).ccls. and @ad<=20000731	IBM_TDB USPAT;	2003/06/17
		· · ·	US-PGPUB; EPO; JPO;	08:22
		·	DERWENT; IBM TDB	
-	403	((257/192).ccls. and @ad<=20000731) and 'FET'	USPAT; US-PGPUB;	2002/05/08
			EPO; JPO; DERWENT;	
_	201	(257/386).ccls. and @ad<=20000731	IBM_TDB USPAT;	2002/05/08
			US-PGPUB; EPO; JPO;	10:17
			DERWENT; IBM TDB	
_	244	(257/387).ccls. and @ad<=20000731	USPAT; US-PGPUB;	2002/05/08 10:26
			EPO; JPO; DERWENT;	
_	111	(257/388).ccls. and @ad<=20000731	IBM_TDB USPAT;	2002/05/08
		(20., 200, 1002)	US-PGPUB; EPO; JPO;	10:32
			DERWENT; IBM TDB	
_	149	(257/389).ccls. and @ad<=20000731	USPAT; US-PGPUB;	2002/05/08 10:37
			EPO; JPO; DERWENT;	
			IBM TDB	

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	r			0000105100
-	259	(257/393).ccls. and @ad<=20000731	USPAT; US-PGPUB;	2002/05/08 10:39
			EPO; JPO;	10.09
			DERWENT;	
			IBM_TDB	
_	315	(257/346).ccls. and @ad<=20000731	USPĀT;	2002/05/08
			US-PGPUB;	10:43
			EPO; JPO;	
			DERWENT; IBM TDB	
1_	93	(257/395).ccls. and @ad<=20000731	USPAT;	2002/05/08
	53	(20./030).0020. and cade 20000/01	US-PGPUB;	10:47
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	67	(257/27).ccls. and @ad<=20000731	USPAT;	2002/05/08
			US-PGPUB;	10:49
			EPO; JPO; DERWENT;	
			IBM TDB	
_	206	(257/69).ccls. and @ad<=20000731	USPAT;	2002/05/08
		(US-PGPUB;	10:54
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	0000/05/00
-	39	(438/247).ccls. and @ad<=20000731	USPAT;	2002/05/08
			US-PGPUB;	10:59
			EPO; JPO; DERWENT;	
			IBM TDB	
_	86	(438/159).ccls. and @ad<=20000731	USPAT;	2002/05/08
		(100, 100, 100, 100, 100, 100, 100, 100,	US-PGPUB;	11:01
}			EPO; JPO;	
			DERWENT;	
			IBM_TDB	2002/05/00
_	177	(438/155).ccls. and @ad<=20000731	USPAT;	2002/05/08
			US-PGPUB; EPO; JPO;	11.03
	-		DERWENT;	{
			IBM TDB	
-	139	(257/348).ccls. and @ad<=20000731	USPAT;	2002/05/08
			US-PGPUB;	11:04
			EPO; JPO;	
			DERWENT;	
	175	language and brancistant	IBM_TDB USPAT;	2003/02/25
_	1/3	'surrounding gate transistor'	USPAT; US-PGPUB;	16:01
			EPO; JPO;	10.01
			DERWENT;	
			IBM_TDB	
-	1842	(257/296).ccls. and @ad<=20000731	USPĀT;	2002/10/02
			US-PGPUB;	10:31
			EPO; JPO;	
			DERWENT;	
_	4811	((257/296) or (257/306) or (257/530) or	IBM_TDB USPAT;	2003/02/26
-	4011	((257/296) or (257/306) or (257/350) or (257/354) or (438/238-239)).CCLS.	US-PGPUB;	09:44
		(20,,001, 01 (100,200 200,,10020.	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
] -	542	((257/296).ccls. and @ad<=20000731) and	USPAT;	2003/02/26
		'surrounding gate transistor' or 'SGT'	US-PGPUB;	09:42
			EPO; JPO;	
	[DERWENT; IBM TDB	
_	166	'surrounding gate transistor' and	USPAT;	2002/10/02
	1 100	Gad<=20000731	US-PGPUB;	10:41
	1		EPO; JPO;	
			DERWENT;	
			IBM_TDB	1

	87	'gate electrode' with 'electric field effect'	USPAT; US-PGPUB;	2002/10/04 09:59
			EPO; JPO; DERWENT;	
_	275	'gate electrode applying'	IBM_TDB USPAT;	2002/10/04
	275	gate electione applying	US-PGPUB; EPO; JPO;	10:02
			DERWENT;	
			IBM_TDB	
_	39	'gate electrode applying' with 'electric field'	USPAT; US-PGPUB;	2002/10/04
		electic field	EPO; JPO;	10.07
			DERWENT;	
	2	gate electrode applying' with	IBM_TDB USPAT;	2002/10/04
-		'electric field' with 'channel'	US-PGPUB;	10:10
			EPO; JPO;	
			DERWENT; IBM TDB	
_	87	'gate electrode applying' and 'electric	USPAT;	2002/10/04
		field' and 'channel'	US-PGPUB;	10:11
			EPO; JPO; DERWENT;	
			IBM TDB	
-	196	'surrounding gate transistor'	USPAT;	2003/02/26
			US-PGPUB; EPO; JPO;	09:30
			DERWENT;	
			IBM_TDB	0000/00/00
_	1	"4979014".PN.	USPAT	2003/02/26
-	1	"5019878".PN.	USPAT	2003/02/26
-	1	"5089870".PN.	USPAT	2003/02/26
-	1	"5115289".PN.	USPAT	2003/02/26
_	1	"5163180".PN.	USPAT	2003/02/26
_	2	("5424227").PN.	USPAT;	2003/02/26
			US-PGPUB;	09:30
			EPO; JPO; DERWENT;	
_	828	((257/192).CCLS.) and @ad<=20000731	IBM_TDB USPAT;	2003/06/16
	020	(\25., 152, .colb.) and gad\-20000131	US-PGPUB;	15:40
			EPO; JPO;	
			DERWENT; IBM TDB	
-	46	((257/196).CCLS.) and @ad<=20000731	USPĀT;	2003/02/26
			US-PGPUB; EPO; JPO;	09:35
			DERWENT;	
		(4057/006)	IBM_TDB	2002/02/25
_	577	((257/296).ccls. and @ad<=20000731) and 'surrounding gate transistor' or 'SGT'	USPAT; US-PGPUB;	2003/02/26
-			EPO; JPO;	
			DERWENT;	
_	23	((257/296).ccls. and @ad<=20000731) and	IBM_TDB USPAT;	2003/02/26
		'surrounding gate transistor'	US-PGPUB;	09:44
1]		EPO; JPO; DERWENT;	!
			IBM_TDB	
-	5205	((257/296) or (257/306) or (257/530) or	USPAT;	2003/02/26
		(257/354) or (438/238-239)).CCLS.	US-PGPUB; EPO; JPO;	09:49
			DERWENT;	
	L		IBM_TDB_	

-	4	(("5670810") or ("5414287")).PN.	USPAT;	2003/02/26
			US-PGPUB;	11:04
ŀ			EPO; JPO;	
1			DERWENT;	
}		,	IBM TDB	
-	2	"20020011612"	USPĀT;	2003/06/16
			US-PGPUB;	15:17
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	506	@ad<=20000731 and 'SGT'	USPAT;	2003/06/17
			US-PGPUB;	08:06
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	174	@ad<=20000731 and surrounding adj1 gate	USPĀT;	2003/06/16
		adj1 transistor	US-PGPUB;	15:41
		-	EPO; JPO;	
			DERWENT;)
			IBM TDB	